



QQQX2.E332185 Electrically-isolated Semiconductor Devices - Component

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MACMIC SCIENCE & TECHNOLOGY CO LTD

E332185

#18 HUASHAN

ZHONG LU

CHANGZHOU, JIANGSU 213022 CHINA

Electrically-isolated semiconductor devices, Single Phase Rectifier Bridge Modules: Models MM, followed by D, followed by 50, 90, 110 or 130, followed by A, followed by 080, 100, 120, 140, 160, 180 or 200, followed by B, DK or DA; Models MM, followed by D, followed by 130, 160, 180, 200 or 220, followed by S, followed by 080, 100, 120, 140, 160, 180 or 200, followed by B, DK or DA.

Electrically-isolated semiconductor devices, Single Phase Rectifier Bridge Modules: Models MM, followed by K, Models MM, followed by K, followed by 25, 40, 60, 90 or 110, followed by A, followed by 080, 120, 160, 180, 200 or 220, followed by B, UA or UK; Models MM, followed by K, followed by 130, 160, 180 or 200, followed by S, followed by 080, 120, 160, 180, 200 or 220, followed by B, UA or UK.

Electrically-isolated semiconductor devices, Three Phase Rectifier Bridge Modules: Models MM, followed by D, followed by 50, followed by L, followed by 080, 100, 120, 140, 160, 180 or 200, followed by X; Models MM, followed by D, followed by 70 or 100, followed by E, followed by 080, 100, 120, 140, 160, 180 or 200, followed by X; Models MM, followed by D, followed by 150, 200, 250 or 260, followed F, followed by 080, 100, 120, 140, 160, 180 or 200, followed by X.

Electrically-isolated semiconductor devices, Three Phase Rectifier Bridge Modules: Models MM, followed by K, followed by 75 or 100, followed by U, followed by 080, 120, 160, 180, 200 or 220, followed by UX; Models MM, followed by K, followed by 150 or 200, followed by T, followed by 080, 120, 160, 180, 200 or 220, followed by UX.

Electrically-isolated semiconductor devices, IGBT Module, GS Type, Models MMG100SR060B, MMG50SR120B, MMG75SR120B, MMG100SR120B, MMG150SR120B, MMG75S060B6EN, MMG100S060B6EN, MMG150S060B6EN, MMG200S060B6EN, MMG100S120B6TN, MMG75S120B6UN, MMG100S120B6UN, MMPS-A, MMPS-F, MMPS-G.

Electrically-isolated semiconductor devices, IGBT Module, GD Type, Models MMG200DR060B, MMG100DR120B, MMG150DR120B, MMG200DR120B, MMG300DR120B, MMG300D060B6N, MMG400D060B6N, MMG300D060B6EN, MMG400D060B6EN, MMG150S120B6TN, MMG200D120B6TN, MMG300D120B6TN, MMG150D120B6UN, MMG200D120B6UN, MMG300D120B6UN, MMG400D120B6TN, MMPS-B, MMPS-H, MMPS-I, MMPS-J, MMPS-K, MMPS-L.

Marking: Company name and model designation.

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